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## **GaAs cathode activation with Cs-K-Sb thin film**

*Monday, 8 May 2023 16:30 (2 hours)*

GaAs cathode is a unique device generating a spin-polarized electron beam by photo-electron effect with a circularly polarized laser illumination. Negative Electron Affinity (NEA) surface which is artificially made has an essential role in spin polarization, but the NEA surface has limited vitality. In this study, we activated GaAs as NEA cathode by evaporating Cs, K, and Sb metal on its cleaned surface. The experimental results including the quantum efficiency spectrum and the lifetime will be presented.

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### **Footnotes**

### **I have read and accept the Privacy Policy Statement**

Yes

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